

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
30	0.0030 at V _{GS} = 10 V	25			
	0.0040 at V _{GS} = 4.5 V	22			

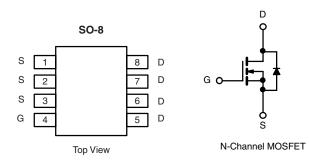
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Gen II
- Ultra Low On-Resistance Using High Density TrenchFET Power MOSFET Technology





- Synchronous Buck Low-Side
 - Notebook
 - Server
 - Workstation
- Synchronous Rectifier-POL



Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V_{GS}	± 20		
Ocationary During Oceany /T., 450,000	T _A = 25 °C	I _D	25	17	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		20	13	
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	70		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Avalanche Current		I _{AS}	50		
	T _A = 25 °C	P _D	3.5	1.6	W
Maximum Power Dissipation ^a	T _A = 70 °C	' D	2.2	1	VV
Operating Junction and Storage Temperature Range		T _J , T _{sta}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	R _{thJA}	29	35		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	67	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

服务热线:400-655-8788

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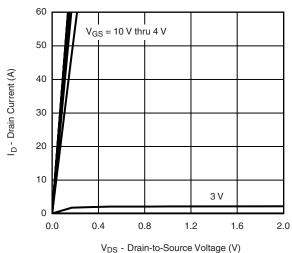
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zoro Cata Valtago Drain Current	1	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	On-State Drain Current ^a I _{D(on)} V		30			Α	
	В	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		0.003			
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		0.004		Ω	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 25 A		110		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.72	1.1	٧	
Dynamic ^b							
Input Capacitance	C _{iss}			6500			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		930		pF	
Reverse Transfer Capacitance	C _{rss}			610			
Total Gate Charge	Q_g			45	70		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		20		nC	
Gate-Drain Charge	Q_{gd}			16			
Gate Resistance	R_g	f = 1.0 MHz		1.1		Ω	
Turn-On Delay Time	t _{d(on)}			27	40		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		21	35		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		107	160	ns	
Fall Time	t _f			43	65		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dl/dt = 100 A/μs		45	70		

Notes:

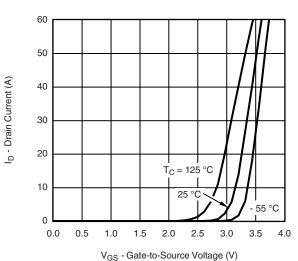
- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Output Characteristics

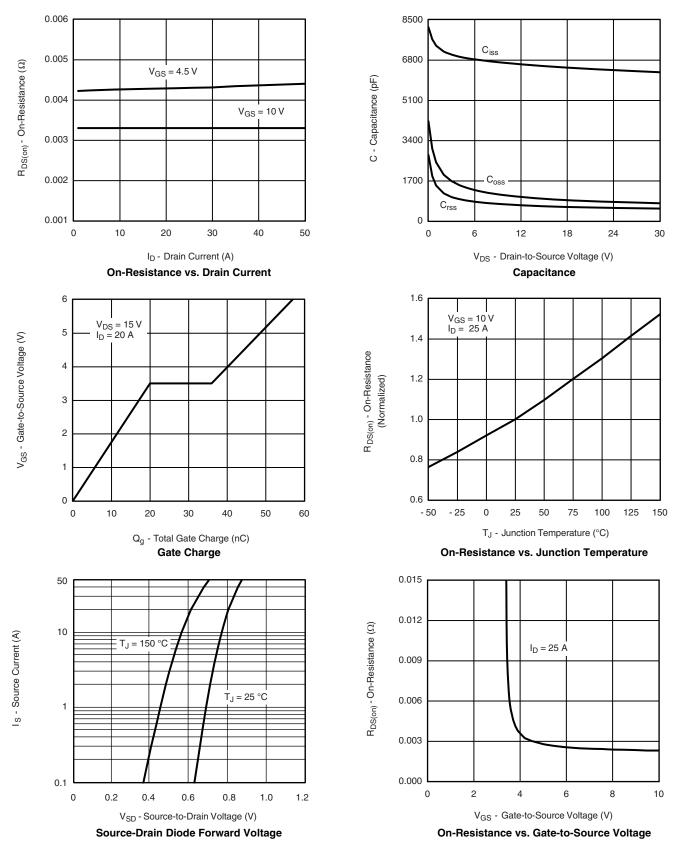


Transfer Characteristics

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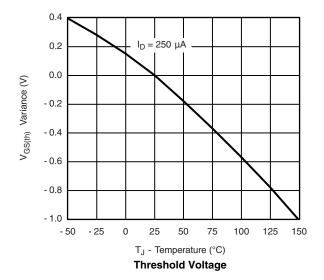


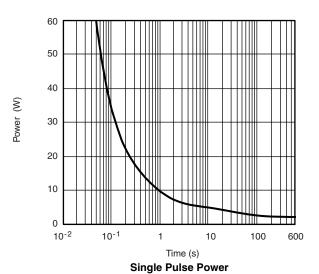
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

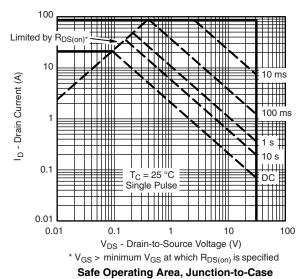




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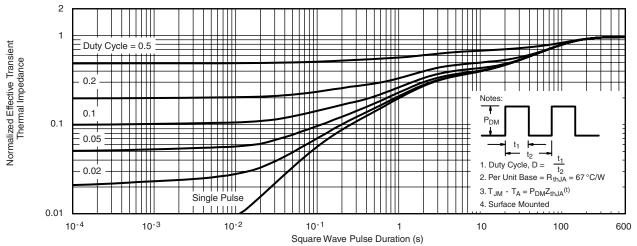




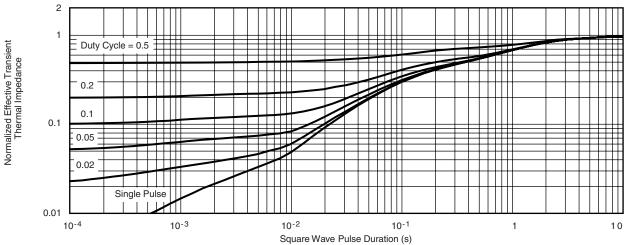
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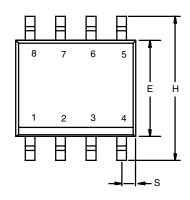
Normalized Thermal Transient Impedance, Junction-to-Ambient

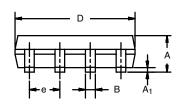


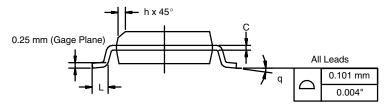
Normalized Thermal Transient Impedance, Junction-to-Foot



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







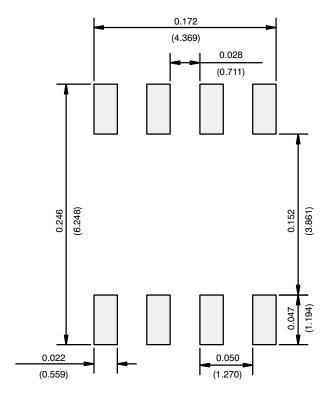
	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06						

DWG: 5498

服务热线:400-655-8788



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)



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